

- Generates Clocks for Next Generation Microprocessors
- Uses a 14.318-MHz Crystal Input to Generate Multiple Output Frequencies
- Includes Spread Spectrum Clocking (SSC), 0.6% Downspread for Reduced EMI With Theoretical EMI of 7 dB
- Power Management Control Terminals
- Low Output Skew and Jitter for Clock Distribution
- Operates From a Single 3.3-V Supply
- Generates the Following Clocks:
  - 8 Host (Diff Pairs, 100/133 MHz)
  - 1 CLK33 (3.3 V, 33.3 MHz)
  - 1 REFCLK (3.3 V, 14.318 MHz)
  - 2 3V48 (3.3 V, 180° Shifted Pairs, 48 MHz)
- Packaged in a 48-Pin TSSOP Package

#### description

The CDC950 is a differential clock synthesizer/driver that generates HCLK/HCLK, CLK33, 3V48, and REFCLK system clock signals to support a computer system with next generation processors and double data rate (DDR) memory subsystems.

All output frequencies are generated from a 14.318-MHz crystal input. A reference clock input can be provided at the XIN input instead of a crystal. Two phase-locked loops (PLLs) are used to generate the host frequencies and the 48-MHz clock frequencies. On-chip loop filters and internal feedback eliminate the need for external components.

The HCLK, CLK33 clock, and 48-MHz clock outputs provide low-skew/low-jitter clock signals for reliable clock operation. All outputs have 3-state capability, which can be selected through control inputs SEL<sup>100</sup>/133, 3V48/SelA, and 3V48/SelB.

The outputs are either differential host clock or 3.3-V single-ended CMOS buffers. With a logic high-level on the PWRDWN terminal, the device operates normally. When a logical low-level input is applied, the device powers down completely with the HOST clock at  $2 \times I_{REF}$ , HOSTB is undriven, CLK33, 3V48, and REFCLK outputs are in a low-level output state and 3V48B is in a high-level output state.

The host bus can operate at 100 MHz or 133 MHz. Output frequency selection is done with the corresponding setting for SEL<sup>100</sup>/133 control input. The CLK33 (PCI) frequency is fixed to 33 MHz.

Since the CDC950 is based on PLL circuitry, it requires a stabilization time to achieve phase-lock of the PLL. This stabilization time is required following power up, as well as following changes to the SEL inputs. With the use of an external reference clock, this signal must be fixed-frequency and fixed-phase prior to stabilization time starts. The CDC950 is characterized for operation from 0°C to 85°C.

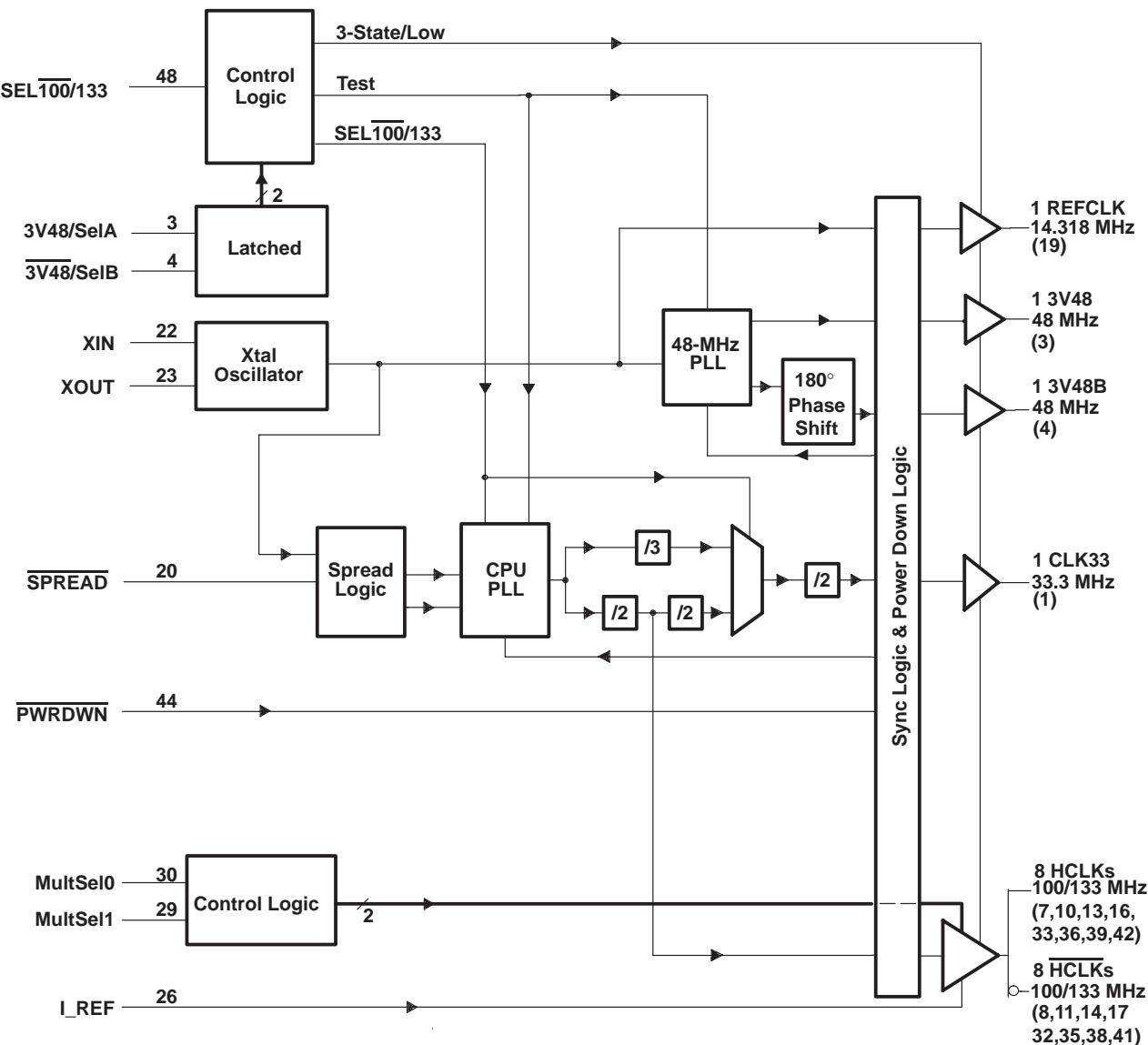
DGG PACKAGE  
(TOP VIEW)

CLK33	1	48	SEL <sup>100</sup> /133
V <sub>DD</sub> 3.3V	2	47	GND
3V48/SelA	3	46	AV <sub>DD</sub> 3.3V
3V48/SelB	4	45	AGND
GND	5	44	PWRDWN
V <sub>DD</sub> 3.3V	6	43	V <sub>DD</sub> 3.3V
HCLK(0)	7	42	HCLK(4)
HCLK(0)	8	41	HCLK(4)
GND	9	40	GND
HCLK(1)	10	39	HCLK(5)
HCLK(1)	11	38	HCLK(5)
V <sub>DD</sub> 3.3V	12	37	V <sub>DD</sub> 3.3V
HCLK(2)	13	36	HCLK(6)
HCLK(2)	14	35	HCLK(6)
GND	15	34	GND
HCLK(3)	16	33	HCLK(7)
HCLK(3)	17	32	HCLK(7)
V <sub>DD</sub> 3.3V	18	31	V <sub>DD</sub> 3.3V
REFCLK	19	30	MultSel0
SPREAD	20	29	MultSel1
GND	21	28	GND
XIN	22	27	AGND
XOUT	23	26	I <sub>REF</sub>
V <sub>DD</sub> 3.3V	24	25	AV <sub>DD</sub> 3.3V



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

## functional block diagram



## Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
3V48/SelA, 3V48/SelB	3, 4	I/O	48-MHz 180° shifted pair clocks for USB use Logic select pins. Selects the mode of operation, see Table 1 for details.
AGND	27, 45	P	Analog ground
AV <sub>DD</sub> 3.3V	25, 46	P	Power. Analog power supply
CLK33	1	O	33-MHz reference clock for PCI use, host clock divided by 3 or by 4
GND	5, 9, 15, 21, 28, 34, 40, 47	P	Ground
HCLK	7, 10, 13, 16, 33, 36, 39, 42	O	CPU and host clock outputs [7:0]. These eight differential CPU clock pairs run at 100/133 MHz. The V <sub>OH</sub> swing amplitude is configured by MultSel0, MultSel1 pins. See Table 5 and Intel's CK00 document for details.
HCLK	8, 11, 14, 17, 32, 35, 38, 41	O	CPU and host clock outputs [7:0]. These eight differential CPU clock pairs run at 100/133 MHz. The V <sub>OH</sub> swing amplitude is configured by MultSel0, MultSel1 pins. See Table 5 and Intel's CK00 document for details.
I_REF	26	I	Current reference. This pin establishes the reference current for host clock parts. See Table 5 and Intel's CK00 document for details.
MultSel0	30	I	See Table 5 and Intel's CK00 document for details.
MultSel1	29	I	See Table 5 and Intel's CK00 document for details.
PWRDWN	44	I	Power-down input. 3.3-V LVTTL compatible, asynchronous input that requests the device to enter the power-down mode. See Table 2 for details.
REFCLK	19	O	14.138-MHz reference clock output: 3.3 V copy of the 14.318-MHz reference clock.
SEL100/133	48	I	Active low LVTTL level logic select. SEL100/133 is used for enabling 100/133 MHz. Low = 100 MHz, high = 133 MHz
SPREAD	20	U	Spread spectrum enable. 3.3-V LVTTL compatible, input that enables the spread spectrum mode when held low. See Table 4 for details.
V <sub>DD</sub> 3.3V	2, 6, 12, 18, 24, 31, 37, 43	P	Power. Power supply
XIN	22	I	Crystal connection or an external reference frequency input. Connect to either a 14.138-MHz crystal or an external reference signal.
XOUT	23	O	Crystal connection. An output connection for an external 14.318-MHz crystal. If using an external reference, this pin must be left unconnected.

## Function Tables

Table 1. Select Functions

INPUTS			OUTPUTS				FUNCTION
SEL100/133	SelA	SelB	HCLK, <u>HCLK</u>	CLK33	3V48, <u>3V48</u>	REFCLK	
0	0	0	100 MHz	33 MHz	48 MHz	14.318 MHz	Active 100 MHz
0	0	1	100 MHz	33 MHz	L, H	14.318 MHz	100 MHz mode; PLL48 powerdown
0	1	0	105 MHz	35 MHz	48 MHz	14.318 MHz	100 MHz mode 5% overclocking
0	1	1	Hi-Z	Hi-Z	Hi-Z	Hi-Z	All 3-state outputs
1	0	0	133 MHz	33 MHz	48 MHz	14.318 MHz	Active 133 MHz
1	0	1	127 MHz	31.7 MHz	48 MHz	14.318 MHz	133 MHz mode -5% underclocking
1	1	0	133 MHz	33 MHz	48 MHz	14.318 MHz	Test mode
1	1	1	TCLK/2	TCLK/8	TCLK/2	TCLK	Test mode (PLL bypass)

Table 2. Enable Functions

INPUT	OUTPUTS					
PWRDWN	HCLK	<u>HCLK</u>	CLK33	3V48	<u>3V48</u>	REFCLK
0	$2 \times I_{REF}$	Hi-Z	L	L	H	L
1	On	On	On	On	On	On

Table 3. Output Buffer Specifications

BUFFER NAME	V <sub>DD</sub> RANGE (V)	IMPEDANCE (Ω)	BUFFER TYPE
3V48, REFCLK	3.135 – 3.465	20–60	TYPE 3
CLK33	3.135 – 3.465	12–55	TYPE 5
HCLK/ <u>HCLK</u>	3.135 – 3.465		TYPE X1

Table 4. Spread Spectrum Functions

INPUT	OUTPUTS	
	SPREAD	
0	Spread spectrum clocking active, -0.6% at HCLK/ <u>HCLK</u> , CLK33	
1	Spread spectrum clocking inactive	

## Function Tables (Continued)

**Table 5. Host/HOST Output Buffer Specifications**

INPUT		BOARD TARGET TRACE/TERM Z	REFERENCE R, $I_{REF} = VDD/(3 Rr)$	OUTPUT CURRENT $I_{OH}$	$V_{OH}$ at Z
MultSel0	MultSel1				
0	0	60 $\Omega$	$Rr = 475$ 1%, $I_{REF} = 2.32$ mA	$5 \times I_{REF}$	0.71 V at 60 $\Omega$
0	0	50 $\Omega$	$Rr = 475$ 1%, $I_{REF} = 2.32$ mA	$5 \times I_{REF}$	0.59 V at 50 $\Omega$
0	1	60 $\Omega$	$Rr = 475$ 1%, $I_{REF} = 2.32$ mA	$6 \times I_{REF}$	0.85 V at 60 $\Omega$
<b>0</b>	<b>1</b>	<b>50 <math>\Omega</math></b>	<b><math>Rr = 475</math> 1%, <math>I_{REF} = 2.32</math> mA</b>	<b><math>6 \times I_{REF}</math></b>	<b>0.71 V at 50 <math>\Omega</math></b>
1	0	60 $\Omega$	$Rr = 475$ 1%, $I_{REF} = 2.32$ mA	$4 \times I_{REF}$	0.56 V at 60 $\Omega$
1	0	50 $\Omega$	$Rr = 475$ 1%, $I_{REF} = 2.32$ mA	$4 \times I_{REF}$	0.47 V at 50 $\Omega$
1	1	60 $\Omega$	$Rr = 475$ 1%, $I_{REF} = 2.32$ mA	$7 \times I_{REF}$	0.99 V at 60 $\Omega$
1	1	50 $\Omega$	$Rr = 475$ 1%, $I_{REF} = 2.32$ mA	$7 \times I_{REF}$	0.82 V at 50 $\Omega$
0	0	30 (dc equivalent)	$Rr = 221$ 1%, $I_{REF} = 5$ mA	$5 \times I_{REF}$	0.75 V at 30 $\Omega$
0	0	25 (dc equivalent)	$Rr = 221$ 1%, $I_{REF} = 5$ mA	$5 \times I_{REF}$	0.62 V at 25 $\Omega$
0	1	30 (dc equivalent)	$Rr = 221$ 1%, $I_{REF} = 5$ mA	$6 \times I_{REF}$	0.90 V at 30 $\Omega$
0	1	25 (dc equivalent)	$Rr = 221$ 1%, $I_{REF} = 5$ mA	$6 \times I_{REF}$	0.75 V at 25 $\Omega$
1	0	30 (dc equivalent)	$Rr = 221$ 1%, $I_{REF} = 5$ mA	$4 \times I_{REF}$	0.60 V at 30 $\Omega$
1	0	25 (dc equivalent)	$Rr = 221$ 1%, $I_{REF} = 5$ mA	$4 \times I_{REF}$	0.5 V at 25 $\Omega$
1	1	30 (dc equivalent)	$Rr = 221$ 1%, $I_{REF} = 5$ mA	$7 \times I_{REF}$	1.05 V at 30 $\Omega$
1	1	25 (dc equivalent)	$Rr = 221$ 1%, $I_{REF} = 5$ mA	$7 \times I_{REF}$	0.84 V at 25 $\Omega$

NOTE: The entries in **boldface** are the primary system configurations of interest. The outputs should be optimized for these configurations.

**absolute maximum ratings over operating free-air temperature (unless otherwise noted)**

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.  
 2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51, except for the through-hole packages, which use a trace length of zero.  
 3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils. For more information, refer to the *Package Thermal Considerations* application note in the *ABT Advanced BiCMOS Technology Data Book*, literature number SCBD002.

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DISSIPATION RATING TABLE

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR <sup>†</sup> ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
DGG	1400 mW	11.2 mW/°C	900 mW	730 mW

<sup>†</sup> This is the inverse of the traditional junction-to-case thermal resistance (R<sub>θJA</sub>) and uses a board-mounted device at 89°C/W

**recommended operating conditions (see Note 4)**

		MIN	NOM <sup>‡</sup>	MAX	UNIT
Supply voltages, V <sub>DD</sub> , AV <sub>DD</sub>		3.135	3.3	3.465	V
High-level input voltage, V <sub>IH</sub>		2			
Low-level input voltage, V <sub>IL</sub>			0.8		
Input voltage, V <sub>I</sub>		-0.3	V <sub>DD</sub> + 0.3		
High-level output current, I <sub>OH</sub>	HCLK/HCLK		-40		mA
	CLK33		-18		
	3V48/SelA and 3V48/SelB		-14		
	REFCLK		-14		
Low-level output current, I <sub>OL</sub>	HCLK/HCLK		0		
	CLK33		12		
	3V48/SelA and 3V48/SelB		9		
	REFCLK		9		
Reference frequency, f(XIN) <sup>§</sup>	Test mode		14		MHz
Crystal, f(XTAL) <sup>¶</sup>	Normal mode	13.8	14.318	14.8	
Operating free-air temperature, T <sub>A</sub>		0	85		°C

<sup>‡</sup> All nominal values are measured at their respective nominal V<sub>DD</sub> values.

<sup>§</sup> Reference frequency is a test clock driven on the XIN input during the device test mode or normal mode. In test mode, XIN can be driven externally up to f(XIN) = 16 MHz. If XIN is driven externally, XOUT is floating.

<sup>¶</sup> This is a series fundamental crystal with f<sub>0</sub> = 14.31818 MHz

NOTE 4: Unused inputs must be held high or low to prevent them from floating.

**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V <sub>IK</sub>	Input clamp voltage	V <sub>DD</sub> = 3.135 V, I <sub>I</sub> = -18 mA				-1.2	V
I <sub>IH</sub>	High-level input current	All inputs except SelA, SelB	V <sub>DD</sub> = 3.465 V, V <sub>I</sub> = V <sub>DD</sub>			5	µA
I <sub>IL</sub>	Low-level input current	All inputs except SelA, SelB	V <sub>DD</sub> = 3.465 V, V <sub>I</sub> = GND			-5	µA
I <sub>OZ</sub>	High-impedance-state output current	All outputs including SelA, SelB	V <sub>DD</sub> = 3.465 V	3V48/SelA, 3V48/SelB = H, SEL100/133 = L, V <sub>O</sub> = V <sub>DD</sub> or GND, PWRDWN = H		±10	µA
I <sub>DD(Z)</sub>	High-impedance-state supply current‡	V <sub>DD</sub> = 3.465 V		3V48/SelA, 3V48/SelB = H, SEL100/133 = L, PWRDWN = H	19	25	mA
I <sub>DD(PD)</sub>	PWRDWN state supply current‡	SelA, SelB = L	VDD Supply		43	47	mA
A <sub>I</sub> DD(PD)		R <sub>(ref)</sub> = 475 Ω PWRDWN = L	AVDD Supply		3.4	4.2	mA
I <sub>DD(D)</sub>	Dynamic supply current‡	V <sub>DD</sub> = 3.465 V, R <sub>ref</sub> = 475 Ω, I <sub>O</sub> = 6 x I <sub>ref</sub>	PWRDWN = H SSC = ON/OFF C <sub>L</sub> = MAX	100 MHz	173	190	mA
A <sub>I</sub> DD	Analog power supply current	V <sub>DD</sub> = 3.465 V		133 MHz	183	200	
C <sub>I</sub>	Input capacitance§	V <sub>DD</sub> = 3.3 V, V <sub>I</sub> = V <sub>DD</sub> or GND		100 MHz and SSC off	19	24	mA
C <sub>(XTAL)</sub>	Crystal load capacitance¶	Effective capacity between C <sub>I</sub> N and C <sub>O</sub> UT		133 MHz and SSC off	26	33	
				100 MHz and SSC on	26	33	
				133 MHz and SSC on	35	45	
					2	5	pF
					13.5	22.5	

† All typical values are measured at their respective nominal V<sub>DD</sub> values.

‡ C<sub>L</sub> = MAX = 5 pF, RS = 33.2 Ω, Rp = 49.9 Ω at HCLK/HCLK (Type X1)

C<sub>L</sub> = MAX = 20 pF, R<sub>L</sub> = 500 Ω at 48 MHz, REF (Type 3)

C<sub>L</sub> = MAX = 30 pF, R<sub>L</sub> = 500 Ω at CLK33 (Type 5)

§ These parameters are assured by design and lab characterization, not 100% production tested.

¶ This is the corresponding capacitive load for the XTAL in this oscillator application (Pierce oscillator)

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

#### HCLK/HCLK (Type X1)

PARAMETER	TEST CONDITIONS		MIN	TYPT <sup>†</sup>	MAX	UNIT
$r_o$	Output resistance		3000			$\Omega$
$V_o$	Output voltage			1.2		V
$I_o$	$V_{DD} = 3.30$ V nom	All combinations of Table 5, See Note 5		-7% $I_{(NOM)}$	7% $I_{(NOM)}$	mA
				-12% $I_{(NOM)}$	12% $I_{(NOM)}$	
$C_o$	Output capacitance	$V_{DD} = 3.30$ V nom	$V_o = V_{DD}$ GND	3.5		pF

NOTE 5:  $I_{(NOM)}$  is output current ( $I_{OH}$ ) of table 5.

#### 3V48, 3V48REFCLK (Type 3)

PARAMETER	TEST CONDITIONS		MIN	TYPT <sup>†</sup>	MAX	UNIT
$V_{OH}$	$V_{DD} = \text{min to max}$ , $I_{OH} = -1$ mA		$V_{DD} = 0.1$			V
	$V_{DD} = 3.135$ V, $I_{OH} = -14$ mA		2.4			
$V_{OL}$	$V_{DD} = \text{min to max}$ , $I_{OL} = 1$ mA		0.1			
	$V_{DD} = 3.135$ V, $I_{OL} = 9$ mA		0.18		0.4	
$I_{OH}$	$V_{DD} = 3.135$ V, $V_o = 1$ V		-29			mA
	$V_{DD} = 3.3$ V, $V_o = 1.65$ V		-37			
	$V_{DD} = 3.465$ V, $V_o = 3.135$ V		-11		-23	
$I_{OL}$	$V_{DD} = 3.135$ V, $V_o = 1.95$ V		29			
	$V_{DD} = 3.3$ V, $V_o = 1.65$ V		39			
	$V_{DD} = 3.465$ V, $V_o = 0.4$ V		16		27	
$C_o$	Output capacitance		$V_{DD} = 3.3$ V, $V_o = V_{DD}$ or GND	4.5	7	pF
$Z_o$	High state	$V_o = 0.5 V_{DD}$ , $V_o/I_{OH}$	20	40	60	$\Omega$
	Low state	$V_o = 0.5 V_{DD}$ , $V_o/I_{OL}$	20	40	60	

<sup>†</sup> All typical values are measured at their respective nominal  $V_{DD}$  values.

**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)**

**CLK33 (Type 5)**

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
V <sub>OH</sub>	High-level output voltage	V <sub>DD</sub> = min to max, I <sub>OH</sub> = -1 mA	V <sub>DD</sub> - 0.1	2.4	0.1	V
		V <sub>DD</sub> = 3.135 V, I <sub>OH</sub> = -18 mA	2.4			
V <sub>OL</sub>	Low-level output voltage	V <sub>DD</sub> = min to max, I <sub>OL</sub> = 1 mA			0.1	mA
		V <sub>DD</sub> = 3.135 V, I <sub>OL</sub> = 12 mA		0.15	0.4	
I <sub>OH</sub>	High-level output current	V <sub>DD</sub> = 3.135 V, V <sub>O</sub> = 1 V	-33	30	-53	mA
		V <sub>DD</sub> = 3.3 V, V <sub>O</sub> = 1.65 V				
		V <sub>DD</sub> = 3.465 V, V <sub>O</sub> = 3.135 V	-16		-33	
I <sub>OL</sub>	Low-level output current	V <sub>DD</sub> = 3.135 V, V <sub>O</sub> = 1.95 V	30	51	21	38
		V <sub>DD</sub> = 3.3 V, V <sub>O</sub> = 1.65 V				
		V <sub>DD</sub> = 3.465 V, V <sub>O</sub> = 0.4 V				
C <sub>O</sub>	Output capacitance	V <sub>DD</sub> = 3.3 V, V <sub>O</sub> = V <sub>DD</sub> or GND	4.5	7.5		pF
Z <sub>o</sub>	Output impedance	High state V <sub>O</sub> = 0.5 V <sub>DD</sub> , V <sub>O</sub> /I <sub>OH</sub>	12	35	55	Ω
		Low state V <sub>O</sub> = 0.5 V <sub>DD</sub> , V <sub>O</sub> /I <sub>OL</sub>	12	35	55	

† All typical values are measured at their respective nominal V<sub>DD</sub> values.

**switching characteristics, V<sub>DD</sub> = 3.135 V to 3.465 V, T<sub>A</sub> = 0°C to 85°C**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>(over)</sub>	Overshoot†		HCLK/HCLK 0.7-V amplitude	V <sub>OH</sub> + 200		V <sub>OL</sub> - 200	mV
V <sub>(under)</sub>							
V <sub>(over)</sub>	Overshoot†		Other clocks, C <sub>L</sub> = worst case	GND - 0.7		V <sub>DD</sub> + 0.7	V
V <sub>(under)</sub>							
t <sub>PZL</sub>	Output enable time from low level	SEL <sub>100/133</sub>	All outputs SEL <sub>100/133</sub> ↑ R <sub>ref</sub> = 475 Ω			10	ns
t <sub>PZH</sub>	Output enable time to high level	SEL <sub>100/133</sub>	All outputs SEL <sub>100/133</sub> ↑ R <sub>ref</sub> = 475 Ω			10	
t <sub>PHZ</sub>	Output disable time from high level	SEL <sub>100/133</sub>	All outputs SEL <sub>100/133</sub> ↓ R <sub>ref</sub> = 475 Ω			10	
t <sub>PLZ</sub>	Output disable time from low level	SEL <sub>100/133</sub>	All outputs SEL <sub>100/133</sub> ↓ R <sub>ref</sub> = 475 Ω			10	
t <sub>s</sub>	Stabilization time‡	V <sub>DD</sub>	All outputs After power up			0.1	ms
		PWRDWN	All outputs From PWRDWN ↑			0.25	ms

† These parameters are assured by design and lab characterization, not 100% production tested.

‡ Stabilization time is the time required for the integrated PLL circuit to obtain phase lock of its feedback signal to its reference signal. In order for phase lock to be obtained, a fixed-frequency, fixed-phase reference signal must be present at XIN. Until phase lock is obtained, the specifications for propagation delay and skew parameters given in the switching characteristics tables are not applicable. Stabilization time is defined as the time since V<sub>DD</sub> achieves its nominal operating level (3.3 V) or PWRDWN transition from a low to a high level (2 V) until the output frequency is stable and operating within specification.

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**switching characteristics,  $V_{DD} = 3.135$  V to  $3.465$  V,  $T_A = 0^\circ\text{C}$  to  $85^\circ\text{C}$  (continued)****HCLK/HCLK (Type X1),  $C_L = 2$  pF,  $R_{ref} = 475 \Omega$ ,  $6 \times R_{ref}$** 

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
HCLK clock period <sup>†</sup>		$f(\text{HCLK}) = 100$ MHz		10	10.2	ns
		$f(\text{HCLK}) = 133$ MHz		7.5	7.65	
$T_{\text{jit(cc)}}$	Cycle-to-cycle jitter	$f(\text{HCLK}) = 100$ or $133$ MHz	SSC off	-80	80	ps
			SSC on	-110	110	
$t_{\text{dc}}$	Duty cycle	$f(\text{HCLK}) = 100$ or $133$ MHz, Crossing point		45%	55%	
$t_{\text{sk(o)}}$	HCLK bus skew	$f(\text{HCLK}) = 100$ or $133$ MHz, Crossing point		70		ps
$t_r$	Rise time <sup>†</sup>	0.7-V amplitude	$V_O = 0.14$ V to $0.56$ V	175	700	ps
	Fall time <sup>†</sup>		$V_O = 0.14$ V to $0.56$ V	175	700	
$V_{(\text{cross})}$	Cross point voltages <sup>†</sup>	0.7-V amplitude	$f(\text{HCLK}) = 100$ or $133$ -MHz HCLK and HCLK		45% $V_{OH}$	55% $V_{OH}$

<sup>†</sup> These parameters are assured by design and lab characterization, not 100% production tested.<sup>†</sup> The average over any 1-μs period of time is greater than the minimum specified period.**CLK33 (Type 5),  $C_L = 30$  pF,  $R_L = 500 \Omega$** 

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
PCI clock period <sup>†</sup>	$f(\text{HCLK}) = 100$ or $133$ MHz	30	30.06	30.6	ns
$T_{\text{jit(cc)}}$	$f(\text{HCLK}) = 100$ or $133$ MHz	-150		150	ps
$t_{(\text{dc})}$	$f(\text{CLK33}) = 33.3$ MHz	45%	55%		
$t_r$	$V_O = 0.4$ V to $2.4$ V	0.5		2	ns
$t_f$	$V_O = 0.4$ V to $2.4$ V	0.5		2	

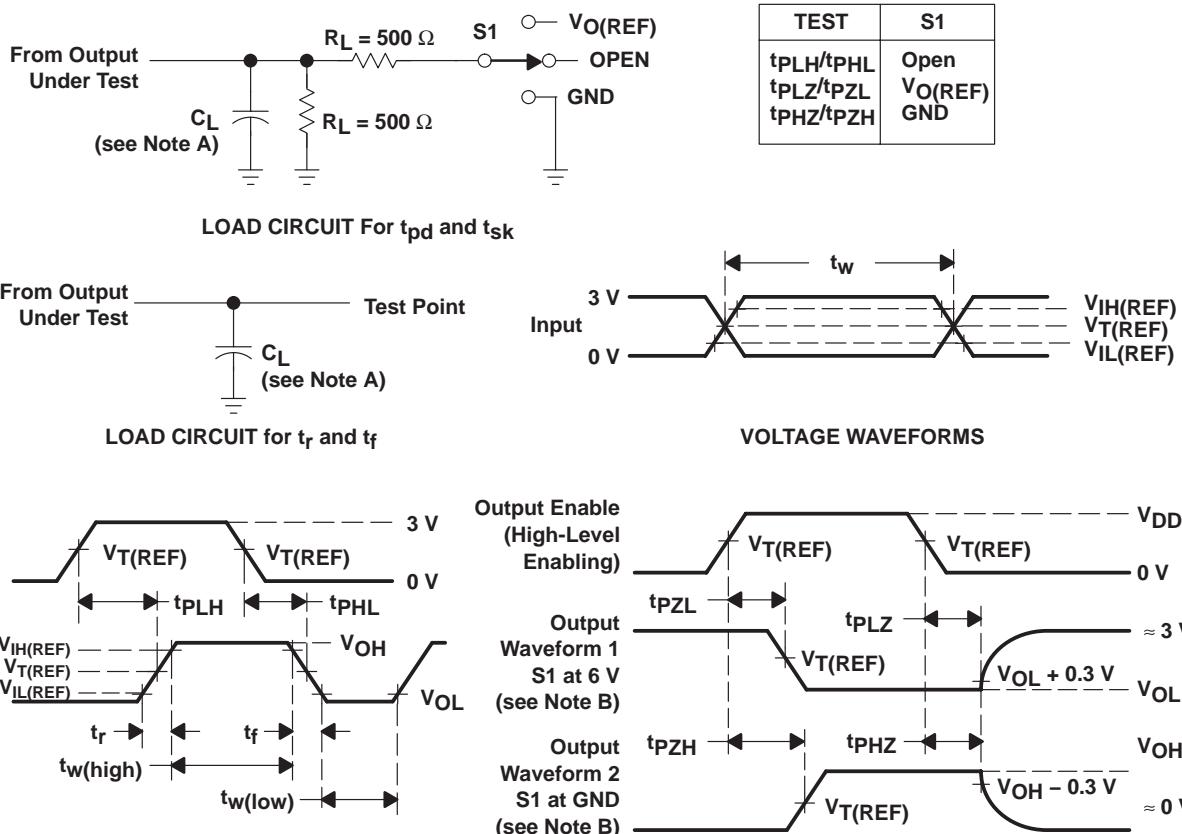
<sup>†</sup> The average over any 1-μs period of time is greater than the minimum specified period.**3V48 (Type 3),  $C_L = 20$  pF,  $R_L = 500 \Omega$** 

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
3V48 clock period	$f(\text{HCLK}) = 100$ or $133$ MHz		20.83		ns
$T_{\text{jit(cc)}}$	$f(\text{HCLK}) = 100$ or $133$ MHz	-300		300	ps
$t_{\text{dc}}$	$f(3V48) = 48$ MHz	45%	55%		
$t_r$	$V_O = 0.4$ V to $2.4$ V	1		4	ns
$t_f$	$V_O = 0.4$ V to $2.4$ V	1		4	

**REF (Type 3),  $C_L = 20$  pF,  $R_L = 500 \Omega$** 

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
REF clock period	$f(\text{REF}) = 14.318$ MHz		69.84		ns
$T_{\text{jit(cc)}}$	$f(\text{HCLK}) = 100$ or $133$ MHz	-0.5		0.5	
$t_{(\text{dc})}$	$f(\text{REF}) = 14.318$ MHz	45%	55%		ns
$t_r$	$V_O = 0.4$ V to $2.4$ V	1		4	
$t_f$	$V_O = 0.4$ V to $2.4$ V	1		4	

## PARAMETER MEASUREMENT INFORMATION



PARAMETER	3.3-V INTERFACE	UNIT
$V_{IH(\text{REF})}$	High-level reference voltage	V
$V_{IL(\text{REF})}$	Low-level reference voltage	
$V_{T(\text{REF})}$	Input threshold reference voltage	
$V_{O(\text{REF})}$	Off-state reference voltage	

Figure 1. Load Circuit and Voltage Waveforms

## APPLICATION INFORMATION

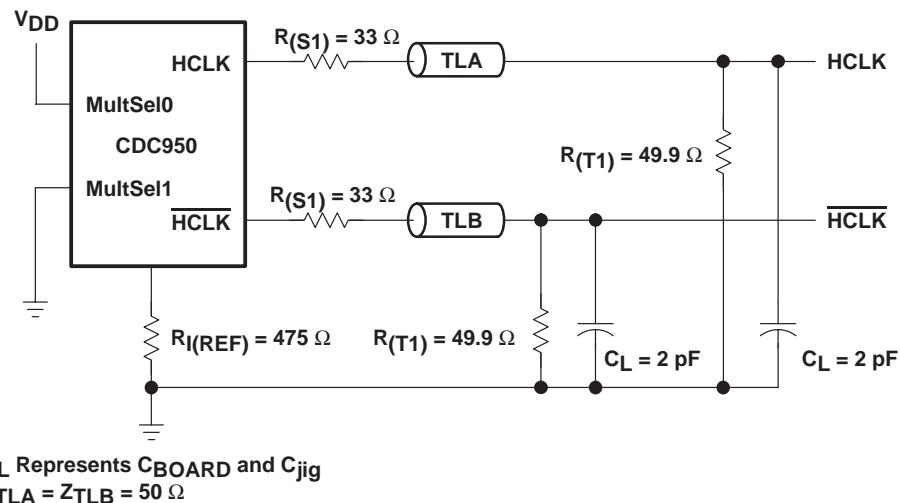


Figure 2. Load Circuit for HCLK Bus

## spread spectrum clock (SSC) implementation for CDC950

Simultaneously switching at a fixed frequency generates a significant power peak at the selected frequency, which in turn causes EMI disturbance to the environment. The purpose of the internal frequency modulation of the CPU-PLL allows energy to be distributed to many different frequencies which reduces the power peak.

A typical characteristic for a single frequency spectrum and a frequency modulated spectrum is shown in Figure 3.

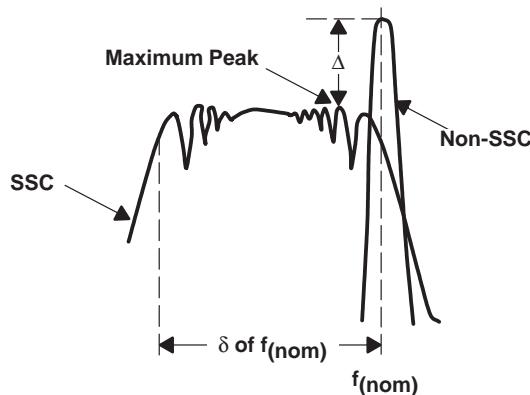


Figure 3. Frequency Power Spectrum With and Without the Use of SSC

The modulated spectrum has its distribution (left side) associated with the single-frequency spectrum which indicates a down-spread modulation.

The peak reduction depends on the modulation scheme and modulation profile. System performance and timing requirements are the limiting factors for actual design implementations. The implementation was driven to keep the average clock frequency close to its upper specification limit. The modulation amount was set to approximately -0.6%.

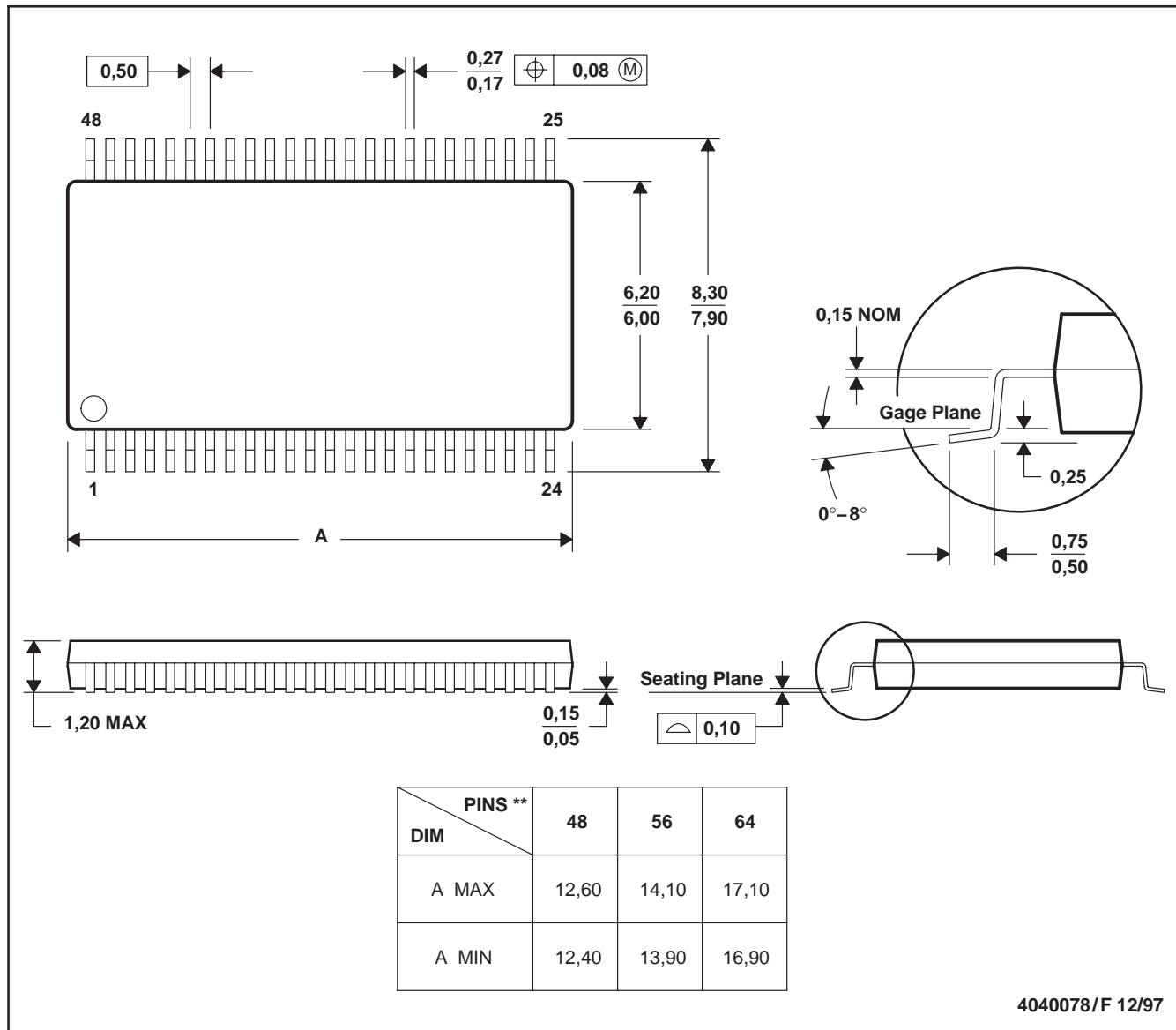
To allow a downstream PLL to follow the frequency modulated signal, the bandwidth of the modulation signal is limited in order to minimize SSC induced tracking skew jitter. The modulation frequency is approximately 31 kHz.

## MECHANICAL DATA

## DGG (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153

**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CDC950DGG	ACTIVE	TSSOP	DGG	48	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CDC950DGGS4	ACTIVE	TSSOP	DGG	48	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CDC950DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CDC950DGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

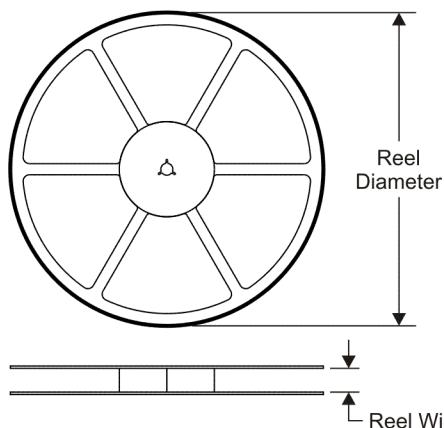
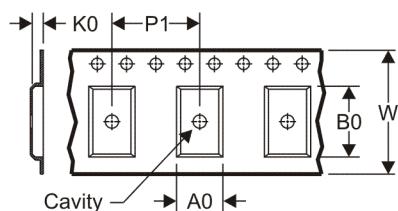
**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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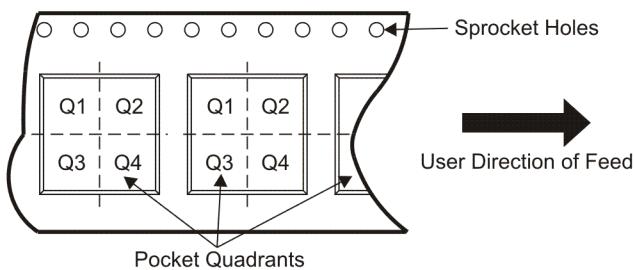
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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**TAPE AND REEL INFORMATION**
**REEL DIMENSIONS**

**TAPE DIMENSIONS**


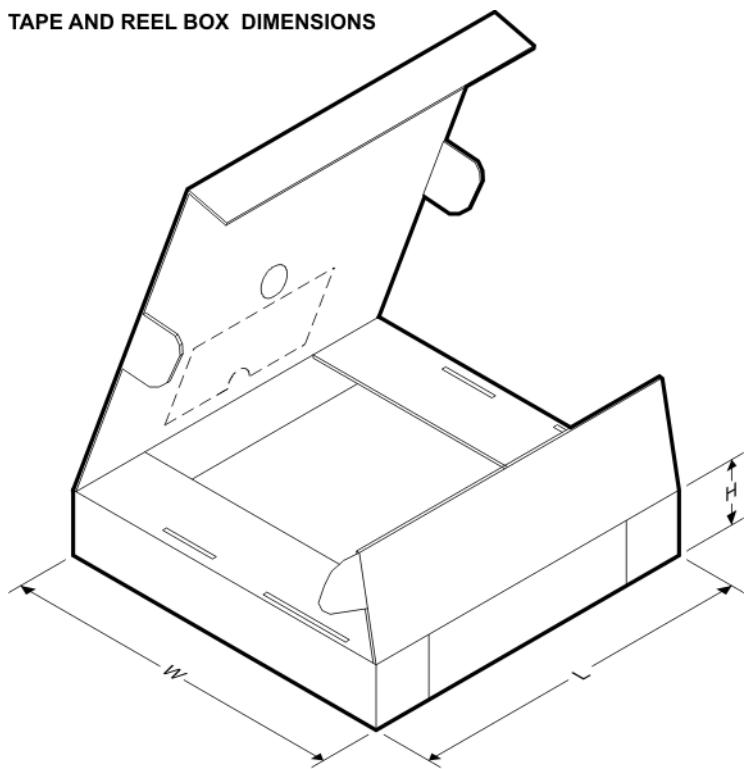
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDC950DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1

**TAPE AND REEL BOX DIMENSIONS**



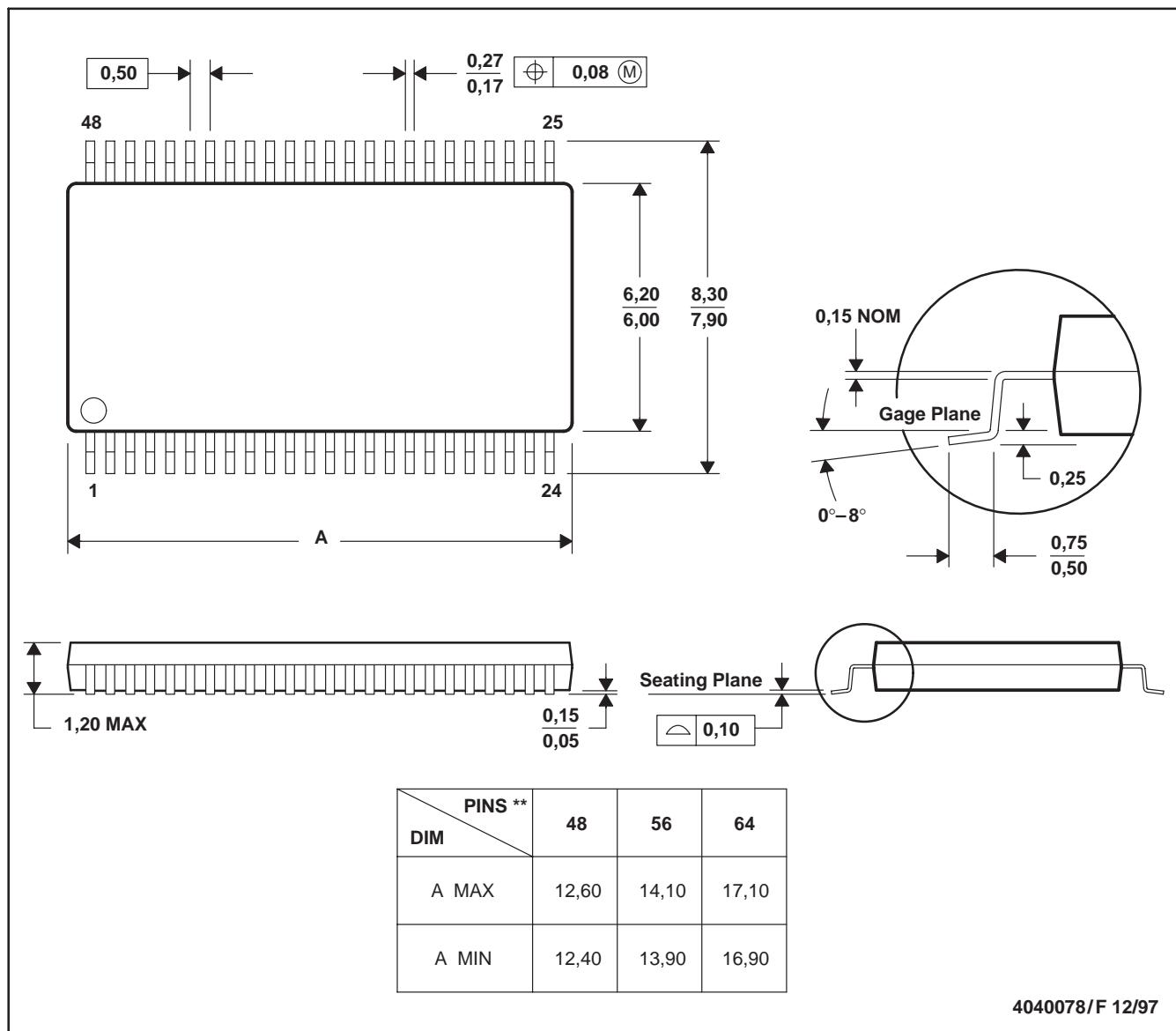
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CDC950DGGR	TSSOP	DGG	48	2000	333.2	345.9	31.8

## DGG (R-PDSO-G\*\*)

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